NSN 5961-01-120-1233

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-120-1233 **Inclosure Material:** Plastic **Overall Length:** 0.600 inches **Overall Height:** 0.190 inches **Overall Width:** 0.410 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 collector to base voltage, dc and 400.0 collector-to-emitter voltage, instantaneous and 5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 1.00 amperes source cutoff current and 0.60 amperes source cutoff current **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 150.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No